

Product Summary

BV_{DSS}	R_{D(S(ON))} Max	I_D Max T_A = +25°C
-30V	7.0mΩ @ V _{GS} = -10V	-18.5A
	10.0mΩ @ V _{GS} = -4.5V	-15.5A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{D(S(ON))}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- Power Management Functions
- DC-DC Converters

Features

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- **ESD Protected Gate**
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- Halogen and Antimony Free. "Green" Device (Note 3)

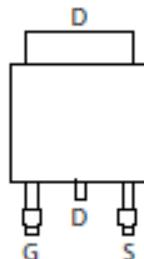
Mechanical Data

- Case: TO252 (DPAK)
- Case Material: Molded Plastic, "Green" Molding Compound; UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Finish - Matte Tin Annealed over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 (E3)
- Weight: 0.315 grams (Approximate)

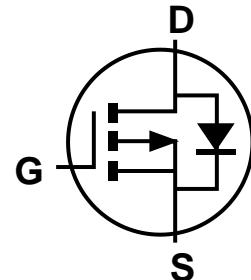
TO252 (DPAK)



Top View



Pin Out Top View



Equivalent Circuit

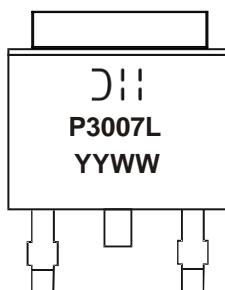
Ordering Information (Note 4)

Part Number	Case	Packaging
DMP3007LK3-13	TO252 (DPAK)	2,500/Tape & Reel

Notes:

1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
2. See <https://www.diodes.com/quality/lead-free/> for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <https://www.diodes.com/design/support/packaging/diodes-packaging/>.

Marking Information



DII = Manufacturer's Marking
 P3007L = Product Type Marking Code
 YYWW = Date Code Marking
 YY = Last Two Digits of Year (ex: 19 = 2019)
 WW = Week Code (01 to 53)

Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic			Symbol	Value	Unit
Drain-Source Voltage			V_{DSS}	-30	V
Gate-Source Voltage			V_{GSS}	± 25	V
Continuous Drain Current, $V_{GS} = -10\text{V}$ (Note 6)	Steady State	$T_A = +25^\circ\text{C}$ $T_A = +70^\circ\text{C}$	I_D	-18.5 -15	A
Maximum Continuous Body Diode Forward Current (Note 6)			I_S	-4.5	A
Pulsed Drain Current (380 μs Pulse, Duty Cycle = 1%)			I_{DM}	-250	A
Pulsed Body Diode Forward Current (380 μs Pulse, Duty Cycle = 1%)			I_{SM}	-250	A
Avalanche Current, $L = 1\text{mH}$ (Note 7)			I_{AS}	-16	A
Avalanche Energy, $L = 1\text{mH}$ (Note 7)			E_{AS}	130	mJ

Thermal Characteristics

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	$T_A = +25^\circ\text{C}$	P_D	1.5	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	$R_{\theta JA}$	81	$^\circ\text{C}/\text{W}$
Total Power Dissipation (Note 6)	$T_A = +25^\circ\text{C}$	P_D	3.0	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	$R_{\theta JA}$	42	$^\circ\text{C}/\text{W}$
Thermal Resistance, Junction to Case (Note 6)		$R_{\theta JC}$	1.5	$^\circ\text{C}/\text{W}$
Operating and Storage Temperature Range		T_J, T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics ($T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV_{DSS}	-30	—	—	V	$V_{GS} = 0\text{V}, I_D = -250\mu\text{A}$
Zero Gate Voltage Drain Current	I_{DSS}	—	—	-1	μA	$V_{DS} = -24\text{V}, V_{GS} = 0\text{V}$
Gate-Source Leakage	I_{GSS}	—	—	± 10	μA	$V_{GS} = \pm 20\text{V}, V_{DS} = 0\text{V}$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	$V_{GS(TH)}$	-1.0	—	-2.8	V	$V_{DS} = V_{GS}, I_D = -250\mu\text{A}$
Static Drain-Source On-Resistance	$R_{DS(ON)}$	—	5.8	7	$\text{m}\Omega$	$V_{GS} = -10\text{V}, I_D = -17\text{A}$
		—	8.2	10		$V_{GS} = -4.5\text{V}, I_D = -15\text{A}$
Diode Forward Voltage	V_{SD}	—	-0.7	-1.2	V	$V_{GS} = 0\text{V}, I_S = -1\text{A}$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	C_{iss}	—	2826	—	pF	$V_{DS} = -15\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Output Capacitance	C_{oss}	—	606	—	pF	
Reverse Transfer Capacitance	C_{rss}	—	305	—	pF	
Gate Resistance	R_g	—	22.8	—	Ω	$V_{DS} = 0\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$
Total Gate Charge ($V_{GS} = -4.5\text{V}$)	Q_g	—	31.2	—	nC	
Total Gate Charge ($V_{GS} = -10\text{V}$)	Q_g	—	64.2	—	nC	
Gate-Source Charge	Q_{gs}	—	10.6	—	nC	
Gate-Drain Charge	Q_{gd}	—	11.6	—	nC	
Turn-On Delay Time	$t_{D(ON)}$	—	4.8	—	ns	
Turn-On Rise Time	t_R	—	4.3	—	ns	$V_{DD} = -15\text{V}, V_{GS} = -10\text{V}, R_g = 6\Omega, I_D = -11.5\text{A}$
Turn-Off Delay Time	$t_{D(OFF)}$	—	306	—	ns	
Turn-Off Fall Time	t_F	—	125	—	ns	
Reverse Recovery Time	t_{RR}	—	19	—	ns	$I_S = -11.5\text{A}, dI/dt = 100\text{A}/\mu\text{s}$
Reverse Recovery Charge	Q_{RR}	—	9.8	—	nC	

Notes:

5. Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^\circ\text{C}$.
8. Short duration pulse test used to minimize self-heating effect.
9. Guaranteed by design. Not subject to product testing.

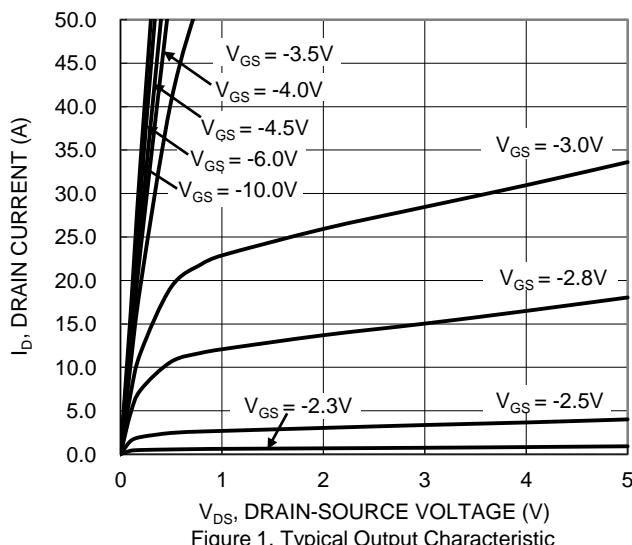


Figure 1. Typical Output Characteristic

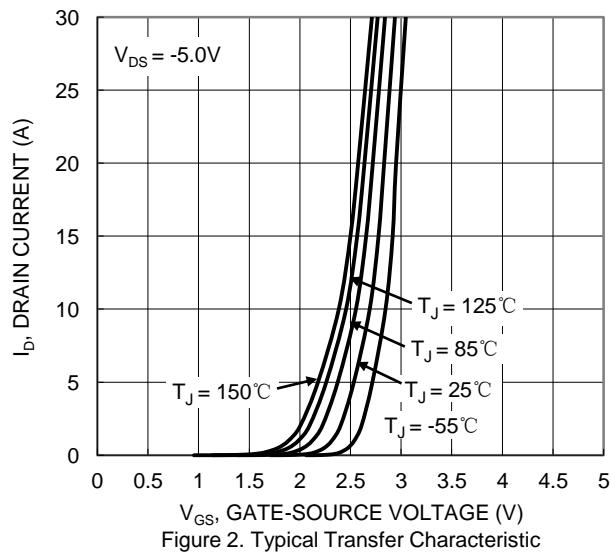


Figure 2. Typical Transfer Characteristic

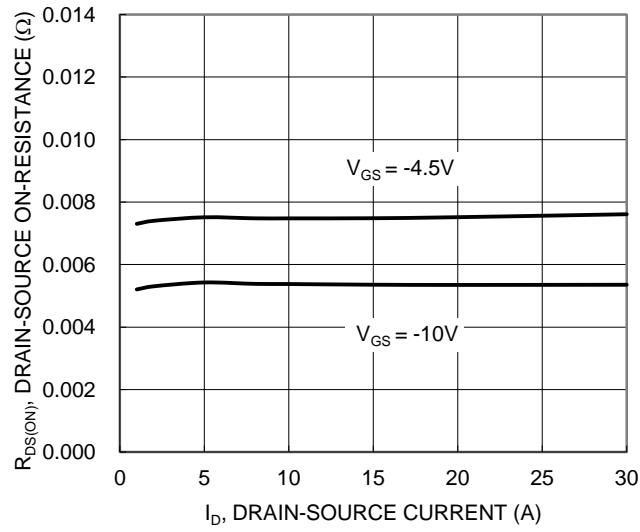


Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

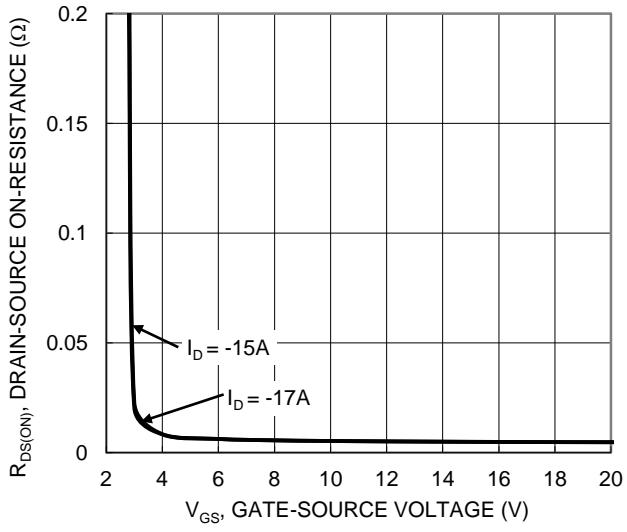


Figure 4. Typical Transfer Characteristic

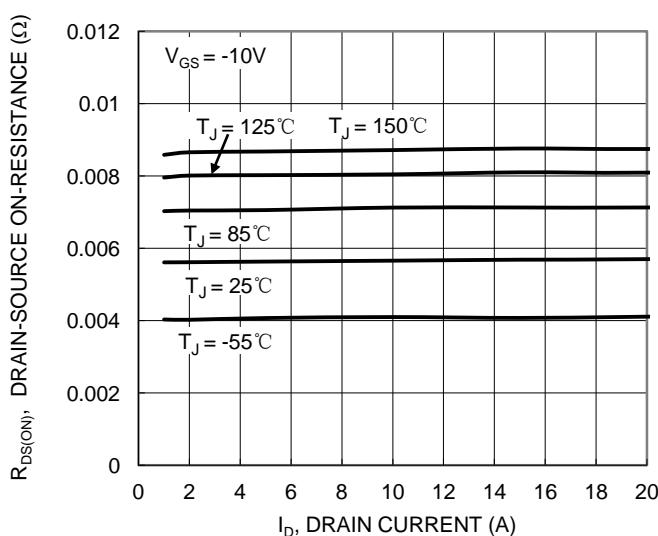


Figure 5. Typical On-Resistance vs. Drain Current and Temperature

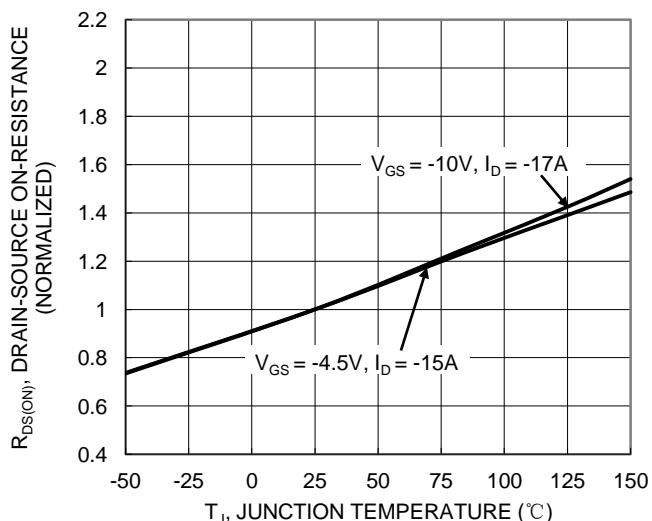
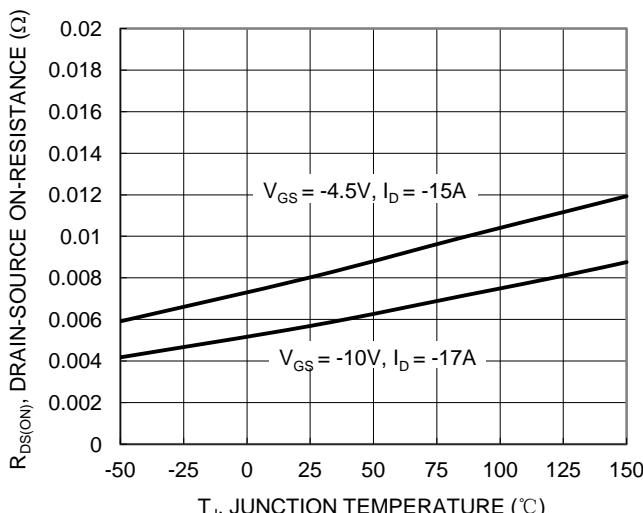
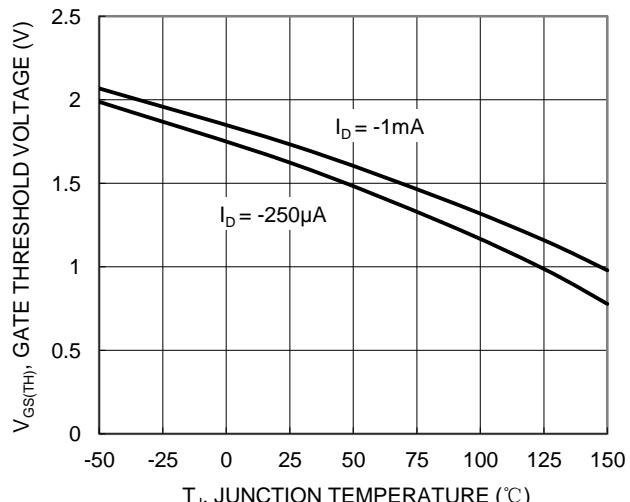


Figure 6. On-Resistance Variation with Temperature



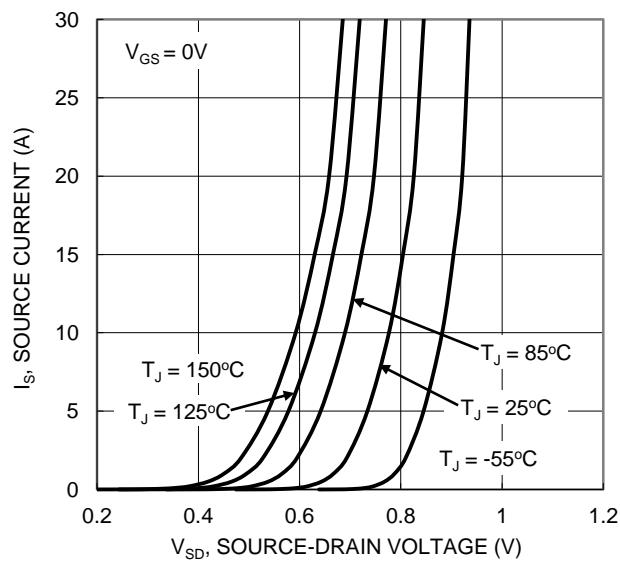
$V_{GS} = -4.5V, I_D = -15A$

$V_{GS} = -10V, I_D = -17A$



$I_D = -1mA$

$I_D = -250\mu A$



$V_{GS} = 0V$

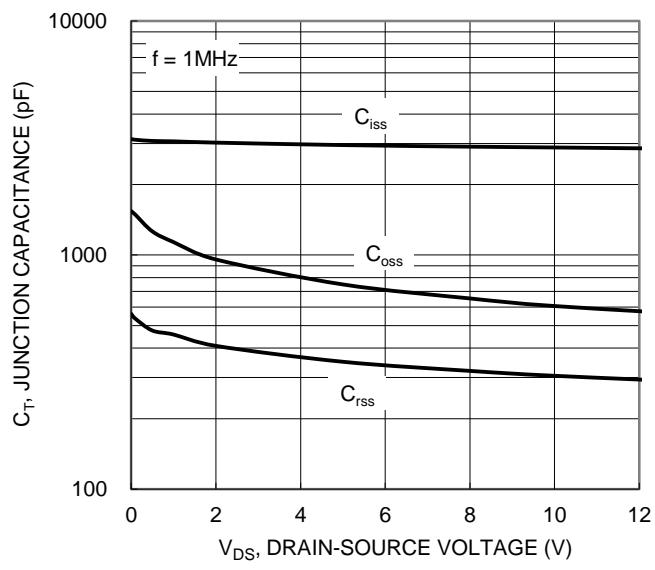
$T_J = 150^\circ C$

$T_J = 125^\circ C$

$T_J = 85^\circ C$

$T_J = 25^\circ C$

$T_J = -55^\circ C$

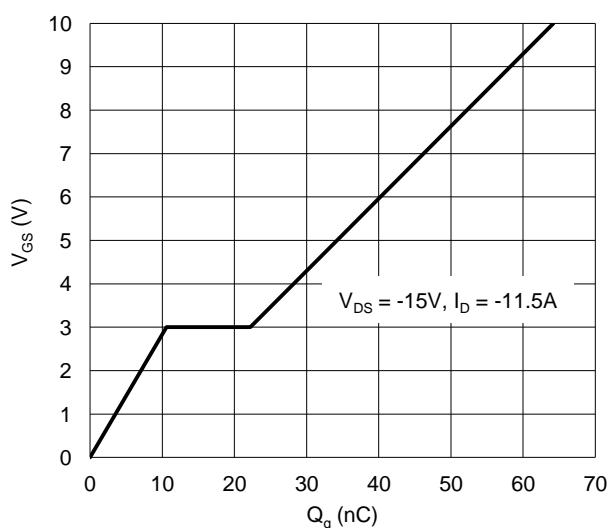


$f = 1MHz$

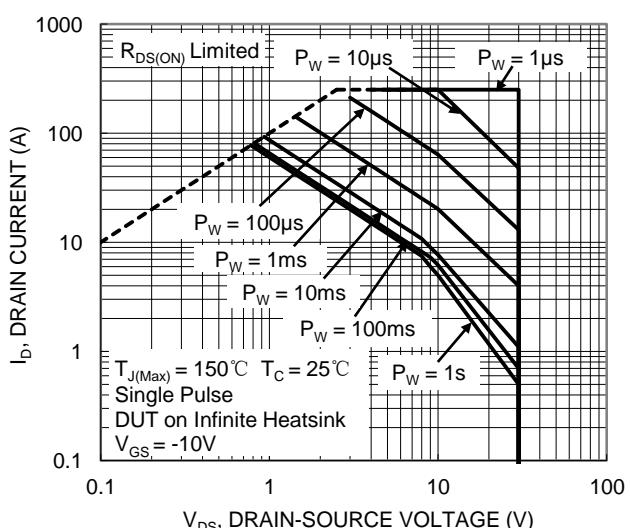
C_{iss}

C_{oss}

C_{rss}



$V_{DS} = -15V, I_D = -11.5A$



$T_{J(\text{Max})} = 150^\circ C$

$T_C = 25^\circ C$

Single Pulse

DUT on Infinite Heatsink

$V_{GS} = -10V$

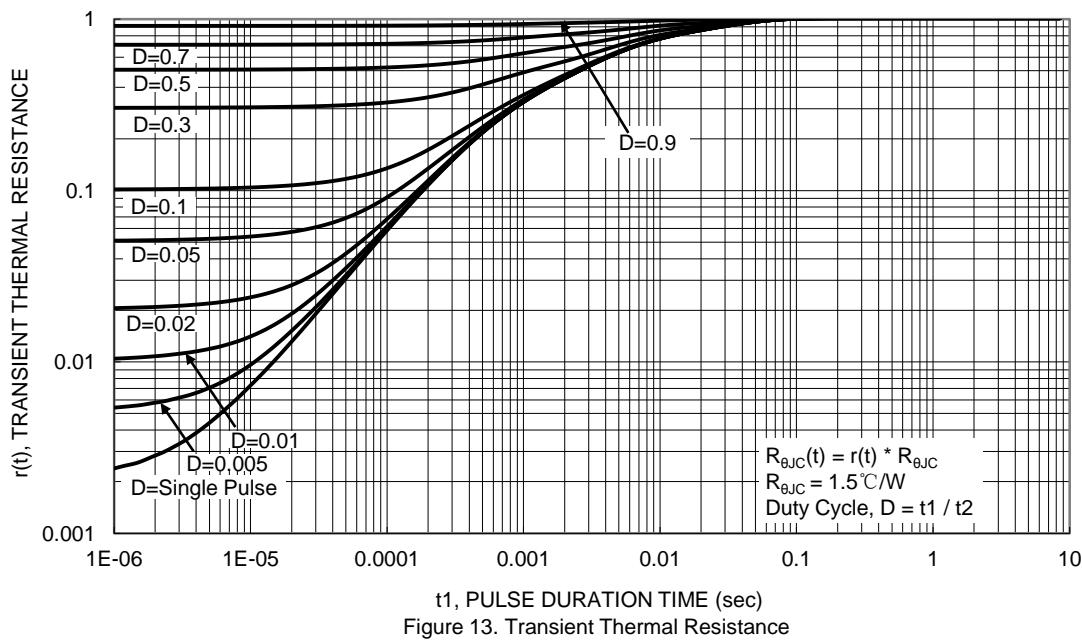
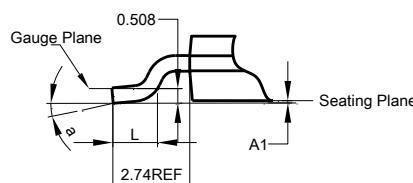
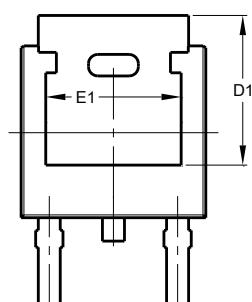
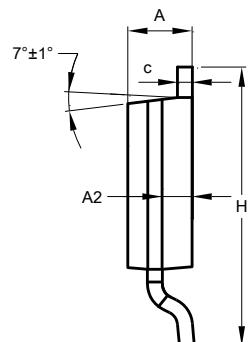
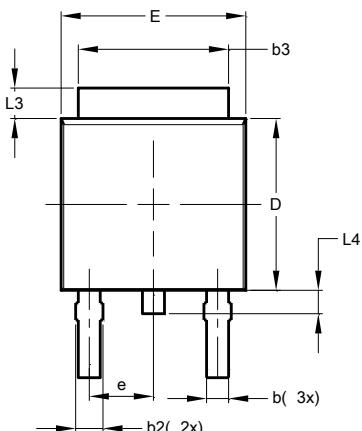


Figure 13. Transient Thermal Resistance

Package Outline Dimensions

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK)



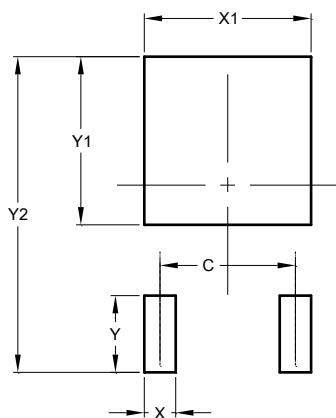
TO252 (DPAK)			
Dim	Min	Max	Typ
A	2.19	2.39	2.29
A1	0.00	0.13	0.08
A2	0.97	1.17	1.07
b	0.64	0.88	0.783
b2	0.76	1.14	0.95
b3	5.21	5.46	5.33
c	0.45	0.58	0.531
D	6.00	6.20	6.10
D1	5.21	-	-
e	-	-	2.286
E	6.45	6.70	6.58
E1	4.32	-	-
H	9.40	10.41	9.91
L	1.40	1.78	1.59
L3	0.88	1.27	1.08
L4	0.64	1.02	0.83
a	0°	10°	-

All Dimensions in mm

Suggested Pad Layout

Please see <http://www.diodes.com/package-outlines.html> for the latest version.

TO252 (DPAK)



Dimensions	Value (in mm)
C	4.572
X	1.060
X1	5.632
Y	2.600
Y1	5.700
Y2	10.700

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